



## **ELECTRONICS**

POLYTEC GmbH

Bürö Berlin ' Schwarzschildstraße 1 ' D - 12489 Berlin ' GERMANY ' wl@pölytec.de
Tel: +49 (30) 63 92 51 40 Fax: +49 (30) 63 92 51 41 www.polytec.de

## MODEL GE SERIES HIGH POWER ACOUSTO-OPTIC MODULATOR DRIVER

## **DESCRIPTION**

The Model GE series high power acousto-optic modulator drivers include a crystal controlled RF oscillator, fast modulation circuit, and a broadband RF power amplifier in a housing with power supply, RFI line filter, line switch, and fault/interlock circuit. The standard crystal controlled oscillator has a calibration tolerance of 25 ppm. Crystals at other than the specified frequencies can be factory installed. The standard modulation input configuration is analog with a digital input option available. A CW RF output level is adjusted by the front panel level control which inserts a dc offset to the input of the modulation circuit with no modulation input voltage. The class AB broadband amplifier has sufficient bandwidth for pulsed operation. RF output power capability can be up to 100 watts for some models. Configuration options include a front panel user



accessible connection between the oscillator and modulation circuit (N) so that an external source frequency can be used in place of the internal crystal oscillator. Also available is an optional front panel connection between the modulation circuit and the RF power amplifier (H) to give the Model GE drivers capability to be used as a stand alone RF power amplifier. The fault/interlock circuit will latch the power supply off when an open circuit condition is present and can be connected to the thermal switch of a Germanium infrared modulator or in a normally closed system interlock circuit.

## **SPECIFICATIONS**

Crystal Oscillator Stability
Input Configuration
RF Amplifier Operation
Rise/Fall Time
Harmonics (at full power)
Output Mismatch Tolerance
Input / Output Impedance
Interlock Input Conditions

Line Voltage (standard)

Size (inches)(cm)

30 ppm

Analog (0-1 volt for 0-maximum RF power)

Class AB 30 nsec -20 dBc

100 percent

50 ohms

Shorted (power supply operational) Open (power supply latched off)

115/230 Vac, 50-60 Hz (100 Vac, option J)

4.5(11.5) H x 16.0(40.7) D x 5.7(14.5) W

MODEL	<b>GE-4030</b>	<b>GE-4050</b>	GE-8030	GE-9020	GE-11020
Oscillator Frequency <sup>1</sup>	40 MHz	40 MHz	80 MHz	90 MHz	110 MHz
RF Output Power <sup>2</sup>	30 watts	50 watts	30 watts	20 watts	20 watts

OPTIONS: D...Inverse digital, input<0.8 volts for RF/on, input>2 volts to 5 volts for RF off, 50 ohm input impedance.

E...Low level oscillator RF output, +10 dBm level.

H...Front panel access between modulator circuit and RF power amplifier.

J...100 Vac for Japan

N...Front panel access between oscillator and modulator circuit.

T...Digital input, input<0.8 volts for RF/off, input>2 volts to 5 volts for RF on, 50 ohm input impedance.

T7...Same as option T (40 dB extinction ratio), but with 70 dB extinction ratio.

-6...Analog input plus option T (2 inputs), total extinction ratio is 70 dB.

<sup>&</sup>lt;sup>1</sup>Other frequencies are available.

<sup>&</sup>lt;sup>2</sup>Other RF power levels are available.